
	<h2 style="color: #E67E22;">NVMF55C426NWFT3G</h2>
	<p>Hersteller-Teilenummer: NVMF55C426NWFT3G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 40V SO8FL</p> <hr/> <p>Datenblätter:  NVMF55C426NWFT3G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

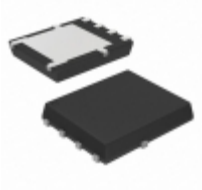
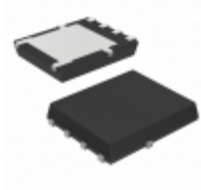
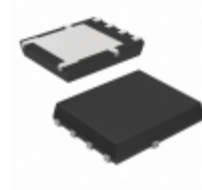
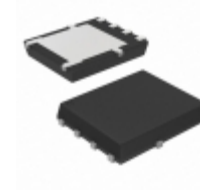
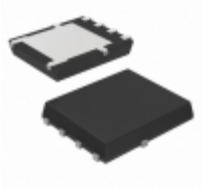
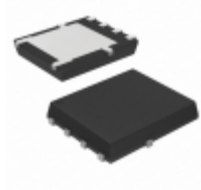
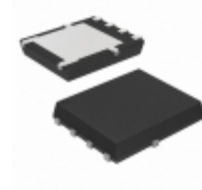
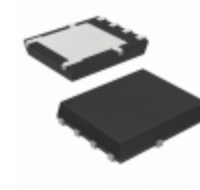
Spezifikationen

Teilenummer	NVMF55C426NWFT3G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 40V SO8FL
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	3.5V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	-
Rds On (Max) @ Id, Vgs	1.3 mOhm @ 50A, 10V
Verlustleistung (max)	3.8W (Ta), 128W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	8-PowerTDFN
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	4300pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	65nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-

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RFQ NVMF55C426NWFT3G E-Mail: Info@Y-IC.com

Sie können auch interessiert

<p>sein:</p>  <p>NVMF55C426NWFT1G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMF55C426NT1G ON Semiconductor MOSFET N-CH 40V SO8FL</p>	 <p>NVMF55C430NLAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A 200A 5DFN</p>	 <p>NVMF55C430NLT1G ON Semiconductor MOSFET N-CH 40V 200A SO8FL</p>
 <p>NVMF55C430NAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 35A 185A 5DFN</p>	 <p>NVMF55C430NAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 35A 185A 5DFN</p>	 <p>NVMF55C426NWFAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 41A 235A 5DFN</p>	 <p>NVMF55C430NLAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 40V 38A 200A 5DFN</p>

Verwandtes Hot-Keyword

Mehr

NVMF55C426NWFT3G AMI Semiconductor / ON Semiconductor	NVMF55C426NWFT3G Datenblatt	NVMF55C426NWFT3G-Datenblätter	NVMF55C426NWFT3G PDF	AMI Semiconductor / ON Semiconductor NVMF55C426NWFT3G
NVMF55C426NWFT3G Electronic	NVMF55C426NWFT3G-Komponenten	NVMF55C426NWFT3G-Verteiler	NVMF55C426NWFT3G-Bild	NVMF55C426NWFT3G-Teil
NVMF55C426NWFT3G Preis	NVMF55C426NWFT3G Hersteller	NVMF55C426NWFT3G Bild	NVMF55C426NWFT3G Aktie	NVMF55C426NWFT3G Inventar
NVMF55C426NWFT3G Neu	NVMF55C426NWFT3G Original	NVMF55C426NWFT3G garantiert	NVMF55C426NWFT3G RFQ	NVMF55C426NWFT3G Online bestellen

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